NSN 5961-01-230-0084

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.250 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.352 inches
Electrode Internally-electrically Connected To Case:
Gate
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 working peak reverse voltage, peak total value, gate terminal open-circuited
Current Rating Per Characteristic:
2.50 amperes forward current, total rms horsepower metric
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius case
Special Features:
Gate sensitivity of 4 ma
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig:
A110a0